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(71) Applicant (for all designated States except US): SEMI-CONDUCTOR ENERGY LABORATORY CO., LTD.
[JP/JP]; 398, Hase, Atsugi-shi, Kanagawa 2430036 (JP).

(72) Inventors; and

(75) Inventors/Applicants (for US only): KUMAKI, Daisuke.
SEO, Satoshi [JP/JP]; c/o SEMICONDUCTOR ENERGY
LABORATORY CO., LTD., 398, Hase, Atsugi-shi, Kana-
gawa 2430036 (JP).

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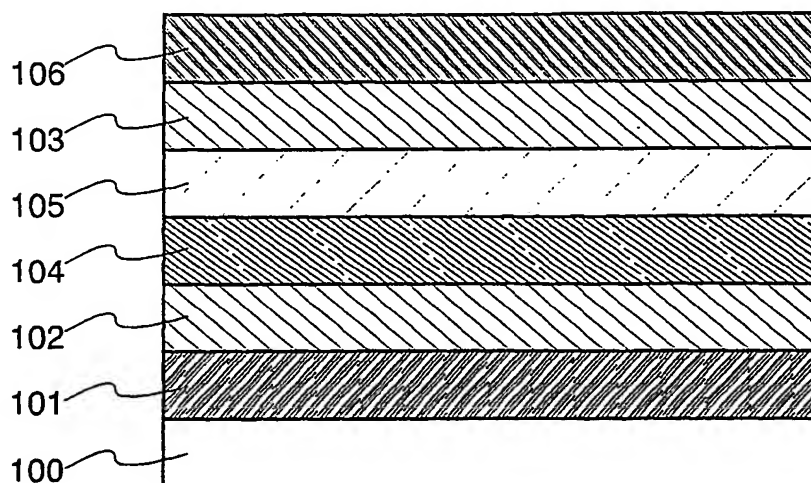
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(54) Title: LIGHT EMITTING DEVICE



(57) Abstract: An object of the present invention is to provide a light emitting element or a light emitting device that can be formed without any regard for a work function of an electrode. Another object of the invention is to provide a light emitting element or a light emitting device in that the range of choice for a material of an electrode can be widened. In an aspect of the invention, a light emitting device includes first, second and third layers between mutually-facing first and second electrodes. The first layer has a donor level. The second layer is a single layer or a laminated body containing a light emitting substance. The third layer has an acceptor level. When a potential of the second electrode is set higher than that of the first electrode, holes generated in the second layer are injected in the third layer.

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